

Power Transistor (−160V , −1.5A)

2SB1275 / 2SB1236A

●Features

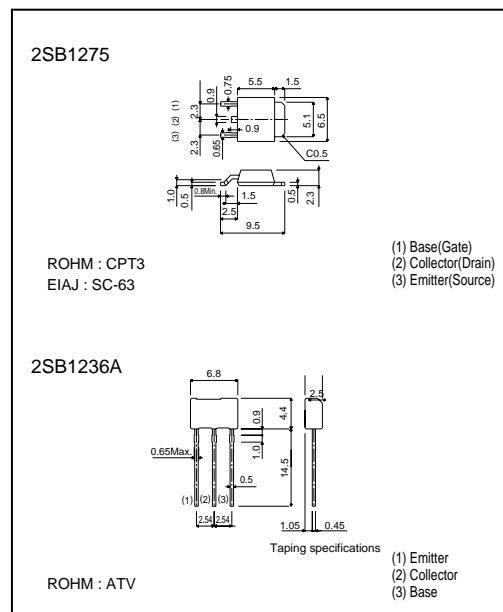
- 1) High breakdown voltage.($BV_{CEO} = -160V$)
- 2) Low collector output capacitance.
(Typ. 30pF at $V_{CB} = 10V$)
- 3) High transition frequency.($f_T = 50MHz$)
- 4) Complements the 2SD1918 / 2SD1857A.

●Absolute maximum ratings ($T_a = 25^\circ C$)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CBO}	−160	V
Collector-emitter voltage	V_{CEO}	−160	V
Emitter-base voltage	V_{EBO}	−5	V
Collector current	I_C	−1.5	A(DC)
		−3	A(Pulse) *1
Collector power dissipation	2SB1275	1	W($T_C = 25^\circ C$)
	2SB1236A	10	
Junction temperature	T_J	1	W
		150	$^\circ C$
Storage temperature	T_{stg}	−55—+150	$^\circ C$

*1 Single pulse. $P_w = 100ms$ *2 Printed circuit board 1.7mm thick, collector plating $1cm^2$ or larger.

●External dimensions (Unit : mm)



●Packaging specifications and hFE

Type	2SB1275	2SB1236A
Package	CPT3	ATV
hFE	P	PQ
Code	TL	TV2
Basic ordering unit (pieces)	2500	2500

●Electrical characteristics ($T_a = 25^\circ C$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CBO}	−160	—	—	V	$I_C = -50\mu A$
Collector-emitter breakdown voltage	BV_{CEO}	−160	—	—	V	$I_C = -1mA$
Emitter-base breakdown voltage	BV_{EBO}	−5	—	—	V	$I_E = -50\mu A$
Collector cutoff current	I_{CBO}	—	—	−1	μA	$V_{CB} = -120V$
Emitter cutoff current	I_{EBO}	—	—	−1	μA	$V_{EB} = -4V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	—	−2	V	$I_C/I_B = -1A/-0.1A$ *
DC current transfer ratio	2SB1275	82	—	180	—	$V_{CE} = -5V$, $I_C = -0.1A$
	2SB1236A	82	—	270	—	
Transition frequency	f_T	—	50	—	MHz	$V_{CE} = -5V$, $I_E = 0.1A$, $f = 30MHz$
Output capacitance	C_{ob}	—	30	—	pF	$V_{CB} = -10V$, $I_E = 0A$, $f = 1MHz$

*Measured using pulse current.

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●Electrical characteristics curves

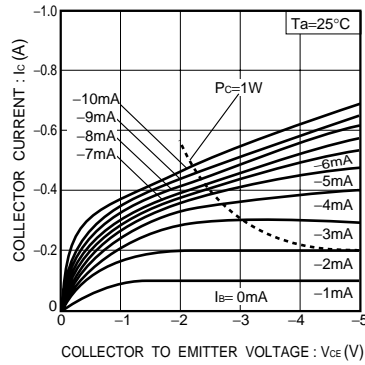


Fig.1 Ground emitter output characteristics

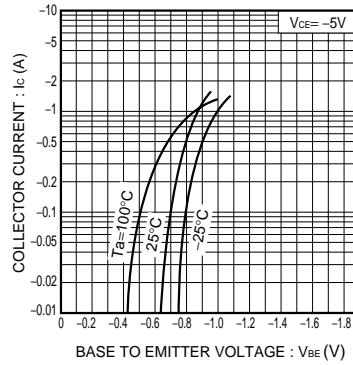


Fig.2 Ground emitter propagation characteristics

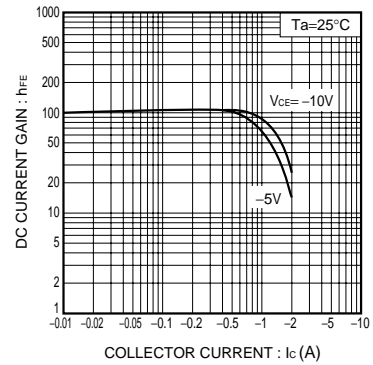


Fig.3 DC current gain vs. collector current (I)

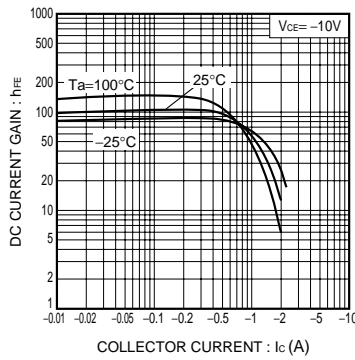


Fig.4 DC current gain vs. collector current (II)

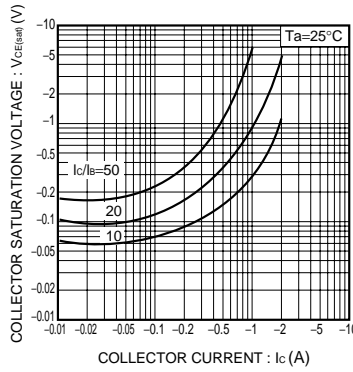


Fig.5 Collector-emitter saturation voltage vs. collector current

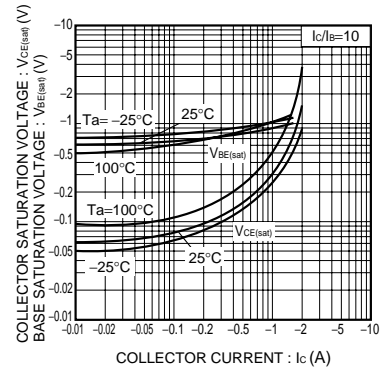


Fig.6 Collector-emitter saturation voltage Base-emitter saturation voltage vs. collector current

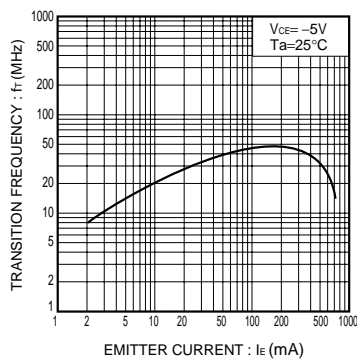


Fig.7 Resistance ratio vs. emitter current

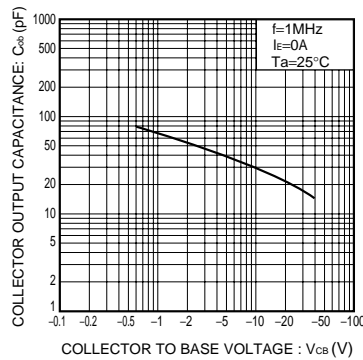


Fig.8 Collector output capacitance vs. collector-base voltage

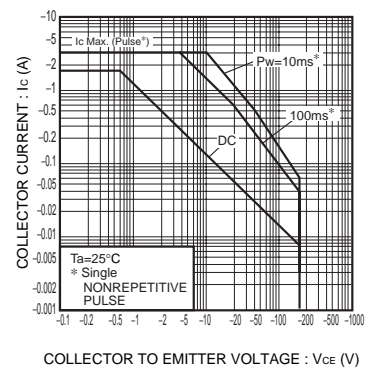
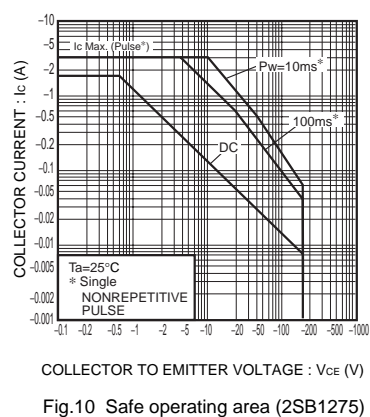


Fig.9 Safe operating area (2SB1236A)

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